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TSV611, TSV611A, TSV612, TSV612A

Rail-to-rail input/output 10 µA, 120 kHz CMOS operational amplifiers

Features

- Rail-to-rail input and output
- Low power consumption: 10 µA typ at 5 V
- Low supply voltage: 1.5 to 5.5 V
- Gain bandwidth product: 120 kHz typ
- Unity gain stable
- Low input offset voltage: 800 µV max (A version)
- Low input bias current: 1 pA typ
- Temperature range: -40 to +85° C

Applications

- Battery-powered applications
- Smoke detectors
- Proximity sensors
- Portable devices
- Signal conditioning
- Active filtering
- Medical instrumentation

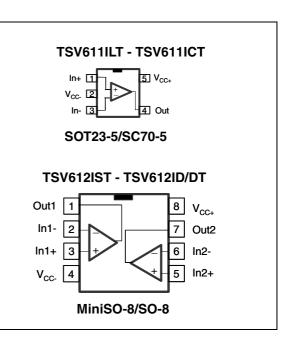
Description

The TSV61x family of single and dual operational amplifiers offers low voltage, low power operation and rail-to-rail input and output.

The devices also feature an ultra-low input bias current as well as a low input offset voltage.

The TSV61x have a gain bandwidth product of 120 kHz while consuming only 10 μA at 5 V.

These features make the TSV61x family ideal for sensor interfaces, battery supplied and portable applications, as well as active filtering.



1

Absolute maximum ratings and operating conditions

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage ⁽¹⁾	6	V
V _{id}	Differential input voltage (2)	±V _{CC}	V
V _{in}	Input voltage ⁽³⁾	V _{CC-} -0.2 to V _{CC+} +0.2	V
T _{stg}	Storage temperature	-65 to +150	°C
	Thermal resistance junction to ambient ⁽⁴⁾⁽⁵⁾		
	SC70-5	205	
R _{thja}	SOT23-5	250	°C/W
	MiniSO-8	190	
	SO-8	125	
Тj	Maximum junction temperature	150	°C
	HBM: human body model ⁽⁶⁾	4	kV
ESD	MM: machine model ⁽⁷⁾	200	V
	CDM: charged device model ⁽⁸⁾	1.5	kV
	Latch-up immunity	200	mA

Table 1. Absolute maximum ratings

1. All voltage values, except differential voltage are with respect to network ground terminal.

2. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.

3. Vcc-Vin must not exceed 6 V.

- 4. Short-circuits can cause excessive heating and destructive dissipation.
- 5. Rth are typical values.
- 6. Human body model: 100 pF discharged through a 1.5 k Ω resistor between two pins of the device, done for all couples of pin combinations with other pins floating.
- Machine model: a 200 pF cap is charged to the specified voltage, then discharged directly between two
 pins of the device with no external series resistor (internal resistor < 5 Ω), done for all couples of pin
 combinations with other pins floating.
- 8. Charged device model: all pins plus package are charged together to the specified voltage and then discharged directly to ground.

Table 2.Operating conditions

Symbol	Parameter	Value	Unit
V _{CC}	Supply voltage	1.5 to 5.5	V
V _{icm}	Common mode input voltage range	V _{CC-} -0.1 to V _{CC+} +0.1	V
T _{oper}	Operating free air temperature range	-40 to +85	°C



2 Electrical characteristics

Table 3.Electrical characteristics at $V_{CC+} = +1.8 V$
with $V_{CC-} = 0 V$, $V_{icm} = V_{CC}/2$, $T_{amb} = 25^{\circ} C$, and R_L connected to $V_{CC}/2$
(unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
DC perfo	ormance			•	•	
V _{io}	Offset voltage	TSV61x TSV61xA			4 0.8	mV
¥ 10	Unset voltage	$T_{min.} < T_{op} < T_{max.} TSV61x$ $T_{min.} < T_{op} < T_{max}TSV61xA$			5 2	ΠV
DV_{io}	Input offset voltage drift			2		μV/°C
	Input offset current			1	10 ⁽¹⁾	pА
I _{io}	$(V_{out} = V_{cc}/2)$	T _{min.} < T _{op} < T _{max.}		1	100	pА
I.,	Input bias current			1	10 ⁽¹⁾	pА
l _{ib}	$(V_{out} = V_{cc}/2)$	T _{min.} < T _{op} < T _{max.}		1	100	pА
CMR	Common mode rejection	0 V to 1.8 V, $V_{out} = 0.9 V$	55	71		dB
	ratio 20 log ($\Delta V_{ic}/\Delta V_{io}$)	T _{min.} < T _{op} < T _{max.}	53			dB
A _{vd}	A _{vd} Large signal voltage gain	$R_L = 10 \text{ k}\Omega$ Vout = 0.5 V to 1.3 V	78	83		dB
, and a second sec		T _{min.} < T _{op} < T _{max.}	74			dB
V _{OH}	High level output voltage	$R_{L} = 10 \text{ k}\Omega$ $T_{\text{min.}} < T_{\text{op}} < T_{\text{max.}}$	35 50	4		mV
V _{OL}	Low level output voltage	$R_{L} = 10 \text{ k}\Omega$ $T_{\text{min.}} < T_{\text{op}} < T_{\text{max.}}$		7	35 50	mV
	Isink	$V_o = 1.8 V$ $T_{min.} < T_{op} < T_{max.}$	9 9	13		
I _{out}	Isource	$V_o = 0 V$ $T_{min.} < T_{op} < T_{max.}$	8 8	10		mA
-	Supply current (per	No load, $V_{out} = V_{cc}/2$	6.5	9	12	μA
I _{CC}	operator)	T _{min.} < T _{op} < T _{max.}	6		12.5	μA
AC perfo	ormance			•	•	•
GBP	Gain bandwidth product	$R_L = 10 \text{ k}\Omega, C_L = 20 \text{ pF}$		100		kHz
φm	Phase margin	$R_L = 10 \text{ k}\Omega, C_L = 20 \text{ pF}$		60		Degrees
G _m	Gain margin	$R_L = 10 \text{ k}\Omega, C_L = 20 \text{ pF}$		9.5		dB
SR	Slew rate	$\label{eq:RL} \begin{split} &R_{L} = 10 \; k\Omega, \;\; C_{L} = 20 \; pF, \\ &V_{out} = 0.5 V \; \text{to} \; 1.3 V \end{split}$		0.03		V/µs



Table 3.Electrical characteristics at $V_{CC+} = +1.8 V$
with $V_{CC-} = 0 V$, $V_{icm} = V_{CC}/2$, $T_{amb} = 25^{\circ} C$, and R_L connected to $V_{CC}/2$
(unless otherwise specified) (continued)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
e _n	Equivalent input noise voltage	f = 1 kHz		110		<u>nV</u> √Hz
THD+N	Total harmonic distortion + noise	$\label{eq:Fin} \begin{array}{l} F_{in} = 1 \text{ kHz}, \text{ Av} = 1, \\ V_{out} = 1 \text{ V}_{pp,} \text{ R}_L = 100 \text{ k}\Omega, \\ BW = 22 \text{ kHz} \end{array}$		0.07		%

1. Guaranteed by design.



Symbol	Parameter		Min.	Тур.	Max.	Unit
DC perfo	ormance					
V _{io} Offset voltage		TSV61x TSV61xA			4 0.8	mV
10		T _{min} <t<sub>op<t<sub>maxTSV61x T_{min}<t<sub>op<t<sub>maxTSV61xA</t<sub></t<sub></t<sub></t<sub>			5 2	
DV_{io}	Input offset voltage drift			2		μV/°C
I _{io}	Input offset current			1	10 ⁽¹⁾	pА
		T _{min.} < T _{op} < T _{max.}		1	100	рА
I _{ib}	Input bias current			1	10 ⁽¹⁾	pА
10		T _{min.} < T _{op} < T _{max.}		1	100	pА
CMR	Common mode rejection	0 V to 3.3 V, $V_{out} = 1.75$ V	61	76		dB
	ratio 20 log ($\Delta V_{ic}/\Delta V_{io}$)	T _{min.} < T _{op} < T _{max.}	58			dB
A _{vd} Large signal voltage gain	$R_L = 10 \text{ k}\Omega$ Vout = 0.5 V to 2.8 V	85	92		dB	
		T _{min.} < T _{op} < T _{max.}	83			dB
V _{OH}	High level output voltage	$\begin{aligned} R_L &= 10 \ k\Omega \\ T_{min.} &< T_{op} < T_{max.} \end{aligned}$	35 50	5		mV
V _{OL}	Low level output voltage			10	35 50	mV
	Isink	V _o = V _{CC} T _{min.} < T _{op} < T _{max.}	37 35	44		0
I _{out}	Isource	$V_o = 0 V$ $T_{min.} < T_{op} < T_{max.}$	32 30	38		mA
	Supply current (per	No load, $V_{out} = V_{CC}/2$	6.5	9.5	12.5	μA
I _{CC}	operator)	T _{min.} < T _{op} < T _{max.}	6		13	μA
AC perfo	ormance					
GBP	Gain bandwidth product	$R_L = 10 \text{ k}\Omega, C_L = 20 \text{ pF}$		110		kHz
φm	Phase margin	$R_L = 10 \text{ k}\Omega, C_L = 20 \text{ pF}$		60		Degrees
G _m	Gain margin	$R_L = 10 \text{ k}\Omega, C_L = 20 \text{ pF},$		9.5		dB
SR	Slew rate	$R_L = 10 k\Omega$, $C_L = 20 pF$, V_{out} = 0.5V to 2.8V		0.035		V/µs
e _n	Equivalent input noise voltage	f = 1 kHz		110		<u>nV</u> √Hz

Table 4. $V_{CC+} = +3.3 \text{ V}$, $V_{CC-} = 0 \text{ V}$, $V_{icm} = V_{CC}/2$, $T_{amb} = 25^{\circ} \text{ C}$, R_L connected to $V_{CC}/2$ (unless otherwise specified)

1. Guaranteed by design.



Symbol	(unless otherwise s	-	Min.	Тур.	Max.	Unit
DC perfo	prmance					
V _{io}	Offset voltage	TSV61x TSV61xA T _{min} <t<sub>op<t<sub>max TSV61x T_{min}<t<sub>op<t<sub>max TSV61xA</t<sub></t<sub></t<sub></t<sub>			4 0.8 5 2	mV
DVio	Input offset voltage drift			2		μV/°C
I _{io}	Input offset current	T _{min.} < T _{op} < T _{max.}		1	10 ⁽¹⁾ 100	рА pA
I _{ib}	Input bias current	T _{min.} < T _{op} < T _{max.}		1	10 ⁽¹⁾ 100	pA pA
CMR	Common mode rejection ratio 20 log $(\Delta V_{ic}/\Delta V_{io})$	$\frac{0 \text{ V to 5 V, V}_{out} = 2.5 \text{ V}}{\text{T}_{min.} < \text{T}_{op} < \text{T}_{max.}}$	64 63	80		dB dB
SVR	Supply voltage rejection ratio 20 log ($\Delta V_{cc}/\Delta V_{io}$)	$\frac{Vcc = 1.8 \text{ to } 5 \text{ V}}{T_{min.} < T_{op} < T_{max.}}$	76 74	93		dB dB
A _{vd}	Large signal voltage gain	$R_L = 10 \text{ k}\Omega$, Vout = 0.5 V to 4.5 V	88	93		dB
		T _{min} <t<sub>op<t<sub>max</t<sub></t<sub>	85			dB
V _{OH}	High level output voltage	$\begin{aligned} R_L &= 10 \ k\Omega \\ T_{min.} &< T_{op} < T_{max.} \end{aligned}$	35 50	7		mV
V _{OL}	Low level output voltage	$\begin{array}{l} R_{L} = 10 \; k\Omega \\ T_{min.} < T_{op} < T_{max.} \end{array}$		16	35 50	mV
I _{out}	lsink	V _o = V _{CC} T _{min.} < T _{op} < T _{max.}	52 42	57		mA
out	Isource	$V_o = 0 V$ $T_{min.} < T_{op} < T_{max.}$	58 49	63		117.
I _{CC}	Supply current (per operator)	No load, $V_{out} = V_{CC}/2$ $T_{min.} < T_{op} < T_{max.}$	7.5 7	10.5	14 15	μA μA
AC perfo	ormance	1 ·		L	1	<u>I</u>
GBP	Gain bandwidth product	$R_L = 10 \text{ k}\Omega, C_L = 20 \text{ pF}$		120		kHz
φm	Phase margin	$R_L = 10 \text{ k}\Omega, C_L = 20 \text{ pF}$		62		Degree
G _m	Gain margin	$R_L = 10 \text{ k}\Omega, C_L = 20 \text{ pF}$		10		dB
SR	Slew rate	$\begin{aligned} R_{L} &= 10 \; k\Omega \; C_{L} = \; 20 \; pF, \\ V_{out} &= 0.5 V \; to \; 4.5 \mathsf{V} \end{aligned}$		0.04		V/µs

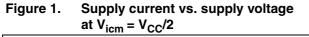
Table 5. $V_{CC+} = +5 V$, $V_{CC-} = 0 V$, $V_{icm} = V_{CC}/2$, $T_{amb} = 25^{\circ} C$, R_L connected to $V_{CC}/2$ (unless otherwise specified)



	(unless otherwise specified) (continued)								
Symbol	Parameter		Min.	Тур.	Max.	Unit			
e _n	Equivalent input noise voltage	f = 1 kHz		105		$\frac{nV}{\sqrt{Hz}}$			
THD+N	Total harmonic distortion + noise	$\label{eq:states} \begin{array}{l} F_{in} = 1 \text{ kHz}, \text{ Av} = 1, \\ V_{out} = 1 V_{pp}, $		0.02		%			

Table 5. $V_{CC+} = +5 V$, $V_{CC-} = 0 V$, $V_{icm} = V_{CC}/2$, $T_{amb} = 25^{\circ} C$, R_{L} connected to $V_{CC}/2$ (unless otherwise specified) (continued)

1. Guaranteed by design.





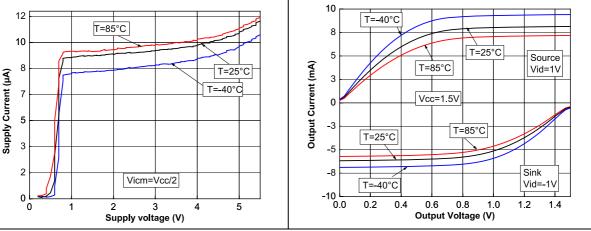


Figure 3. Output current vs. output voltage at Figure 4. $V_{CC} = 5 V$

Voltage gain and phase vs. frequency at $V_{CC} = 1.5 V$

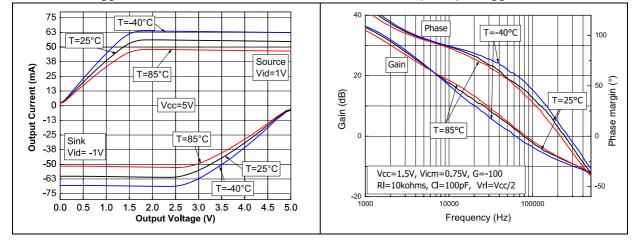




Figure 5. Voltage gain and phase vs. frequency at $V_{CC} = 5 V$

Figure 6. Phase margin vs. output current

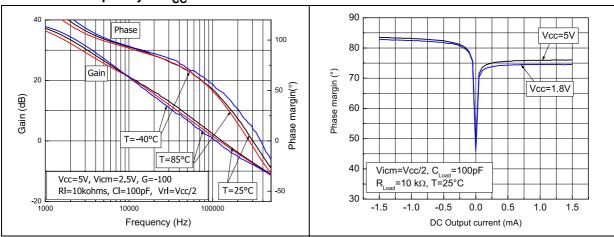


Figure 7. Positive slew rate vs. time, V_{CC} = 1.5 V, Figure 8. C_{Load} = 100 pF, R_{Load} = 10 k Ω

Negative slew rate vs. time, V_{CC} = 1.5 V, C_{Load} = 100 pF, R_{Load} = 10 k Ω

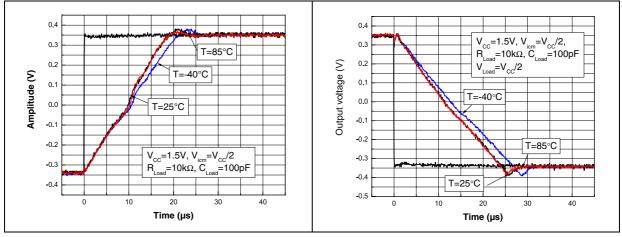
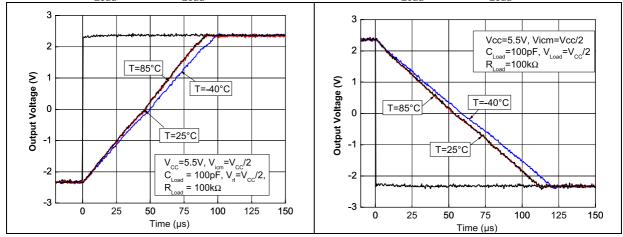
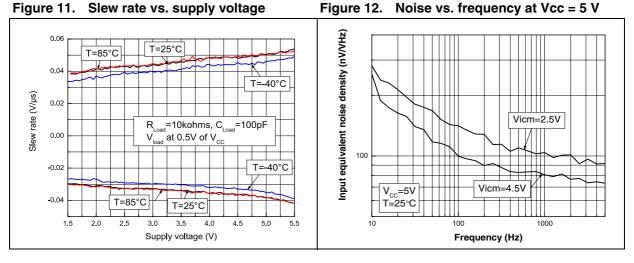


Figure 9.Positive slew rate vs. time, $V_{CC} = 5.5 \text{ V}$, Figure 10.Negative slew rate vs. time, $V_{CC} = 5.5 \text{ V}$, $C_{Load} = 100 \text{ pF}$, $R_{Load} = 100 \text{ k}\Omega$ $C_{Load} = 100 \text{ pF}$, $R_{Load} = 100 \text{ k}\Omega$







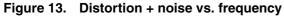
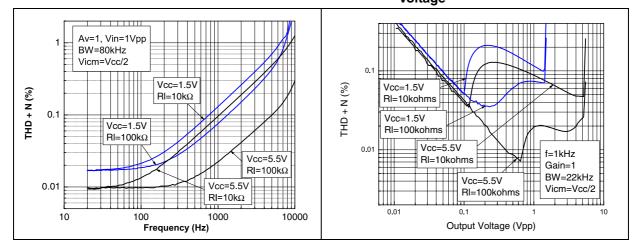
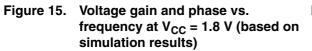
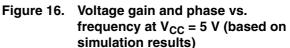
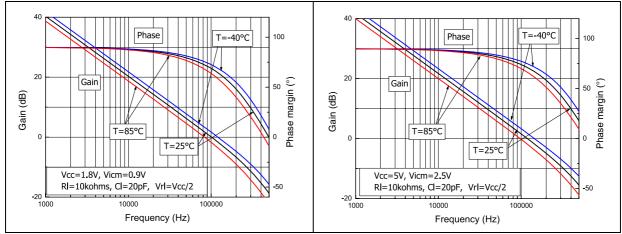


Figure 14. Distortion + noise vs. output voltage











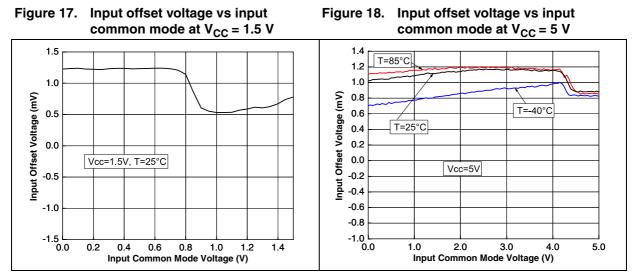
3 Application information

3.1 Operating voltages

The TSV61x can operate from 1.5 to 5.5 V. Their parameters are fully specified for 1.8, 3.3 and 5 V power supplies. However, the parameters are very stable in the full V_{CC} range and several characterization curves show the TSV61x characteristics at 1.5 V. Additionally, the main specifications are guaranteed in extended temperature ranges from -40° C to +85° C.

3.2 Rail-to-rail input

The TSV61x are built with two complementary PMOS and NMOS input differential pairs. The devices have a rail-to-rail input, and the input common mode range is extended from $V_{CC_{-}}$ -0.1 V to $V_{CC_{+}}$ +0.1 V. The transition between the two pairs appears at $V_{CC_{+}}$ -0.7 V. In the transition region, the performance of CMRR, PSRR, V_{io} and THD is slightly degraded (as shown in *Figure 17* and *Figure 18* for V_{io} vs. V_{icm}).



The device is guaranteed without phase reversal.

3.3 Rail-to-rail output

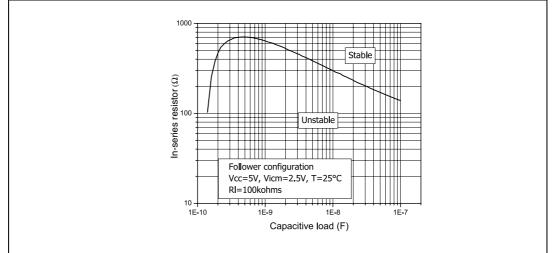
The operational amplifiers' output levels can go close to the rails: less than 35 mV above GND rail and less than 35 mV below V_{CC} rail when connected to 10 k Ω load to $V_{CC}/2$.

3.4 Driving resistive and capacitive loads

These products are micro-power, low-voltage operational amplifiers optimized to drive rather large resistive loads, above 10 k Ω For lower resistive loads, the THD level may significantly increase.



In a follower configuration, these operational amplifiers can drive capacitive loads up to 100 pF with no oscillations. When driving larger capacitive loads, adding an in-series resistor at the output can improve the stability of the devices (see *Figure 19* for recommended in-series resistor values). Once the in-series resistor value has been selected, the stability of the circuit should be tested on bench and simulated with the simulation model.





3.5 PCB layouts

For correct operation, it is advised to add 10 nF decoupling capacitors as close as possible to the power supply pins.

3.6 Macromodel

An accurate macromodel of the TSV61x is available on STMicroelectronics' web site at www.st.com. This model is a trade-off between accuracy and complexity (that is, time simulation) of the TSV61x operational amplifiers. It emulates the nominal performances of a typical device within the specified operating conditions mentioned in the datasheet. It also helps to validate a design approach and to select the right operational amplifier, *but it does not replace on-board measurements*.



4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.



4.1 SOT23-5 package information

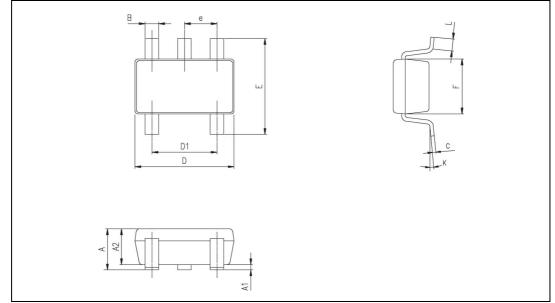


Figure 20. SOT23-5 package mechanical drawing

Table 6. SOT23-5 package mechanical data

	Dimensions								
Ref.	Millimeters			Inches					
	Min.	Тур.	Max.	Min.	Тур.	Max.			
А	0.90	1.20	1.45	0.035	0.047	0.057			
A1			0.15			0.006			
A2	0.90	1.05	1.30	0.035	0.041	0.051			
В	0.35	0.40	0.50	0.013	0.015	0.019			
С	0.09	0.15	0.20	0.003	0.006	0.008			
D	2.80	2.90	3.00	0.110	0.114	0.118			
D1		1.90			0.075				
е		0.95			0.037				
E	2.60	2.80	3.00	0.102	0.110	0.118			
F	1.50	1.60	1.75	0.059	0.063	0.069			
L	0.10	0.35	0.60	0.004	0.013	0.023			
К	0 degrees		10 degrees						



4.2 SC70-5 (SOT323-5) package information

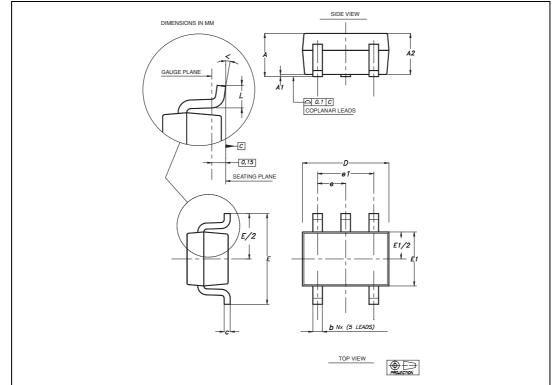


Figure 21. SC70-5 (SOT323-5) package mechanical drawing

Table 7.	SC70-5 (SOT323-5) package mechanical data

		,,	Dimer	nsions		
Ref	Millimeters					
	Min	Тур	Мах	Min	Тур	Max
А	0.80		1.10	0.315		0.043
A1			0.10			0.004
A2	0.80	0.90	1.00	0.315	0.035	0.039
b	0.15		0.30	0.006		0.012
С	0.10		0.22	0.004		0.009
D	1.80	2.00	2.20	0.071	0.079	0.087
E	1.80	2.10	2.40	0.071	0.083	0.094
E1	1.15	1.25	1.35	0.045	0.049	0.053
е		0.65			0.025	
e1		1.30			0.051	
L	0.26	0.36	0.46	0.010	0.014	0.018
<	0°		8°			



4.3 SO-8 package information



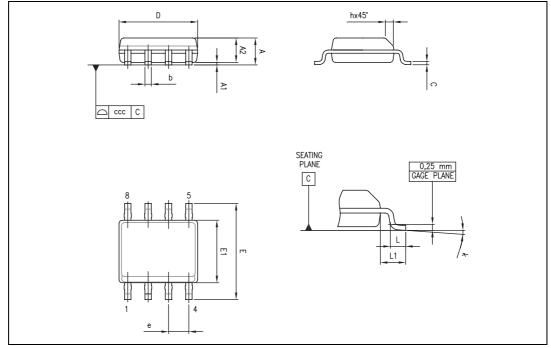


Table 8. SO-8 package mechanical data

Ref.	Millimeters					
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			1.75			0.069
A1	0.10		0.25	0.004		0.010
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
С	0.17		0.23	0.007		0.010
D	4.80	4.90	5.00	0.189	0.193	0.197
Е	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
е		1.27			0.050	
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
L1		1.04			0.040	
k	1°		8°	1°		8°
CCC			0.10			0.004



4.4 MiniSO-8 package information

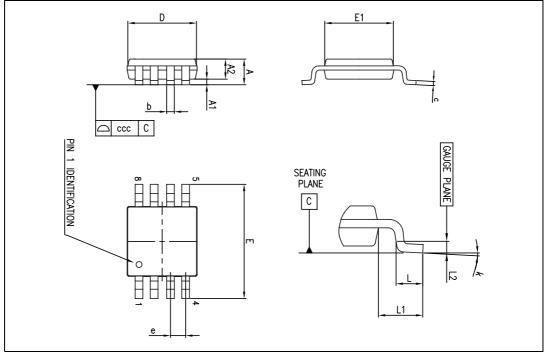


Figure 23. MiniSO-8 package mechanical drawing

Table 9. MiniSO-8 package mechanical data	Table 9.	MiniSO-8	package	mechanical	data
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Ref.	Dimensions							
	Millimeters			Inches				
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А			1.1			0.043		
A1	0		0.15	0		0.006		
A2	0.75	0.85	0.95	0.030	0.033	0.037		
b	0.22		0.40	0.009		0.016		
С	0.08		0.23	0.003		0.009		
D	2.80	3.00	3.20	0.11	0.118	0.126		
Е	4.65	4.90	5.15	0.183	0.193	0.203		
E1	2.80	3.00	3.10	0.11	0.118	0.122		
е		0.65			0.026			
L	0.40	0.60	0.80	0.016	0.024	0.031		
L1		0.95			0.037			
L2		0.25			0.010			
k	0°		8°	0°		8°		
CCC			0.10			0.004		



5 Ordering information

Table 10. Order codes

Order code	Temperature range	Package	Packing	Marking
TSV611ILT		SOT23-5	Tape & reel	K12
TSV611AILT				K11
TSV611ICT		SC70-5		K12
TSV611AICT	-40° C to 85° C			K11
TSV612ID/DT	-40 C 10 85 C	SO-8	Tube & tape & reel	V612I
TSV612AID/DT				V612AI
TSV612IST		MiniSO-8	Tape & reel	K113
TSV612AIST				K115



6 Revision history

Table 11.Document revision history

Date	Revision	Changes
28-May-2009	1	Initial release.
18-Jan-2010	2	Full datasheet for product now in production. Added <i>Figure 1</i> to <i>Figure 19</i> .



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